

TC4042BP/BF

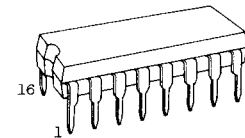
C²MOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC

TC4042BP/TC4042BF QUAD CLOCKED "D" LATCH

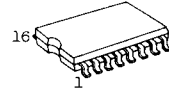
TC4042BP/BF contains four circuits of "D" type latches having common CLOCK input and POLARITY input.

When POLARITY input is placed at "H" level, D input appears as it is at Q output during CLOCK input stays high and D input at the time of falling edge of CLOCK input is retained at Q output. As long as CLOCK input stays low, Q output is not changed even when D input varies.

When POLARITY input is placed "L", D input appears as it is at Q output during CLOCK input stays at "L" level and the latch operation is seen as long as CLOCK input is "H".



DIP16 (3D16A-P)

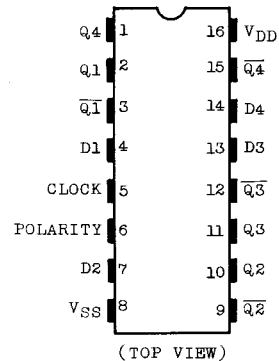


MFP16 (F16GC-P)

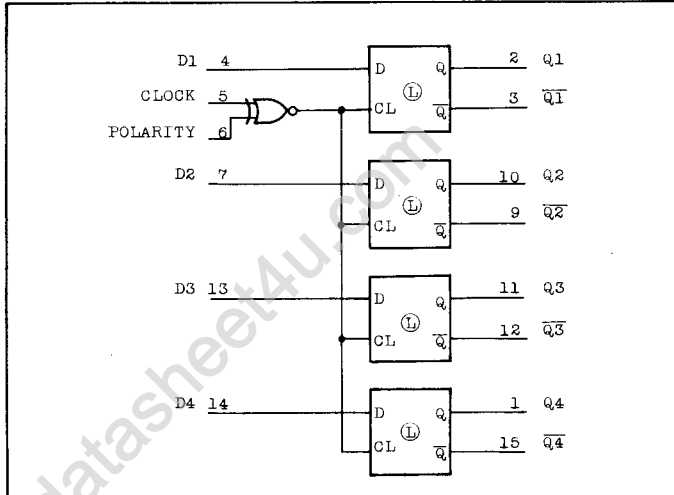
ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNITS
DC Supply Voltage	V _{DD}	V _{SS} - 0.5 ~ V _{SS} + 20	V
Input Voltage	V _{IN}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
Output Voltage	V _{OUT}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
DC Input Current	I _{IN}	±10	mA
Power Dissipation	P _D	300(DIP)/180(MFP)	mW
Operating Temperature Range	T _A	-40 ~ 85	°C
Storage Temperature Range	T _{stg}	-65 ~ 150	°C
Lead Temp./Time	T _{sol}	260°C · 10 sec	

PIN ASSIGNMENT



BLOCK DIAGRAM



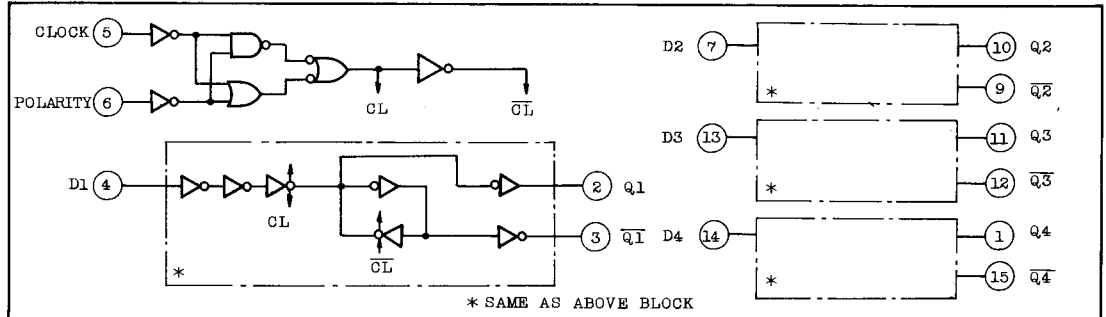
TRUTH TABLE

INPUTS		OUTPUTS
CLOCK Δ	POLARITY ∇	Q _n *
H	H	D _n
L	L	D _n
	L	LATCH
	H	LATCH

Δ : Level Change

* : 1 ~ 4

LOGIC DIAGRAM



RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	V _{DD}	3	-	18	V
Input Voltage	V _{IN}	0	-	V _{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V _{DD} (V)	-40°C		25°C			85°C		UNITS
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Output Voltage	V _{OH}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	4.95	-	4.95	5.00	-	4.95	-	V
			10	9.95	-	9.95	10.00	-	9.95	-	
			15	14.95	-	14.95	15.00	-	14.95	-	
Low-Level Output Voltage	V _{OL}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	-	0.05	-	0.00	0.05	-	0.05	V
			10	-	0.05	-	0.00	0.05	-	0.05	
			15	-	0.05	-	0.00	0.05	-	0.05	
Output High Current	I _{OH}	V _{OH} =4.6V V _{OH} =2.5V V _{OH} =9.5V V _{OH} =13.5V V _{IN} =V _{SS} , V _{DD}	5	-0.61	-	-0.51	-1.0	-	-0.42	-	mA
			5	-2.5	-	-2.1	-4.0	-	-1.7	-	
			10	-1.5	-	-1.3	-2.2	-	-1.1	-	
			15	-4.0	-	-3.4	-9.0	-	-2.8	-	
Output Low Current	I _{OL}	V _{OL} =-0.4V V _{OL} =0.5V V _{OL} =1.5V V _{IN} =V _{SS} , V _{DD}	5	0.61	-	0.51	1.2	-	0.42	-	mA
			10	1.5	-	1.3	3.2	-	1.1	-	
			15	4.0	-	3.4	12.0	-	2.8	-	
			5	3.5	-	3.5	2.75	-	3.5	-	
Input High Voltage	V _{IH}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	5	3.5	-	3.5	2.75	-	3.5	-	V
			10	7.0	-	7.0	5.5	-	7.0	-	
			15	11.0	-	11.0	8.25	-	11.0	-	
			5	-	1.5	-	2.25	1.5	-	1.5	
Input Low Voltage	V _{IL}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	10	-	3.0	-	4.5	3.0	-	3.0	-
			15	-	4.0	-	6.75	4.0	-	4.0	-

TC4042BP/BF

STATIC ELECTRICAL CHARACTERISTICS (Continued)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V _{DD} (V)	-40°C		25°C			85°C		UNITS	
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
Input Current	"H" Level	I _{IH}	V _{IH} =18V	18	-	0.1	-	10 ⁻⁵	0.1	-	1.0	μA
	"L" Level	I _{IL}	V _{IL} =0V	18	-	-0.1	-	-10 ⁻⁵	-0.1	-	-1.0	
Quiescent Device Current	I _{DD}	V _{IN} =V _{SS} , V _{DD}	5	-	1	-	0.002	1	-	30		
			10	-	2	-	0.004	2	-	60		
			15	-	4	-	0.008	4	-	120		

* All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (T_a=25°C, V_{SS}=0V, C_L=50pF)

CHARACTERISTICS	SYMBOL	TEST CONDITION	V _{DD} (V)	MIN.	TYP.	MAX.	UNITS		
								Output Transisition Time (Low to High)	t _{TLH}
Output Transition Time (High to Low)	t _{THL}		5 10 15	- - -	70 35 30	200 100 80			
Propagation Delay Time (CLOCK - Q, Q̄)	t _{pLH} t _{pHL}		5 10 15	- - -	150 70 50	440 180 120			
		Propagation Delay Time (DATA - Q, Q̄)	t _{pLH} t _{pHL}	5 10 15	- - -	110 55 40	220 110 80		
				Min. Clock Pulse Width	t _w	5 10 15	- - -	55 25 20	200 100 60
Min. Hold Time (DATA - CLOCK)	t _H					5 10 15	- - -	5 3 2	50 20 20
		Min. Set-up Time (DATA - CLOCK)	t _{SU}			5 10 15	- - -	20 10 5	50 30 25
				Input Capacitance	C _{IN}		-	5	7.5

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

